## **Electronic Supplementary Information (ESI)**

## Synthesis and photovoltaic property of fine and uniform Zn<sub>2</sub>SnO<sub>4</sub> nanoparticles

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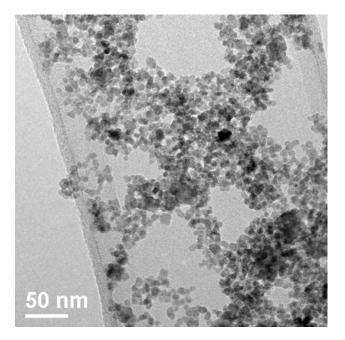


Fig. S1 Low magnified TEM image of  $Zn_2SnO_4$  nanoparticles (NPs) that was synthesized by a hydrothermal reaction with ammonium carbonate (AC) addition as much as the AC/Zn mole ratio of 0.5 at 180 °C for 12 h.

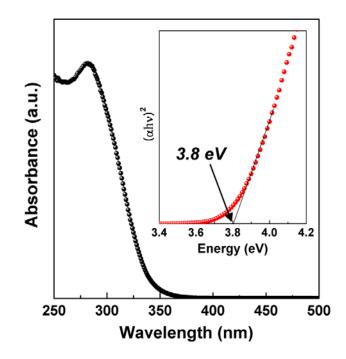


Fig. S2 Optical absorption spectrum of  $Zn_2SnO_4$  NPs; inset, corresponding band gap

determination.

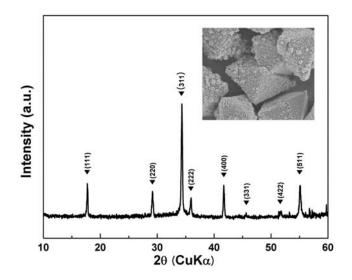


Fig. S3 XRD pattern and SEM image  $Zn_2SnO_4$  powder synthesized by a hydrothermal reaction

without AC addition at 200  $^{\rm o}C$  for 12 h.

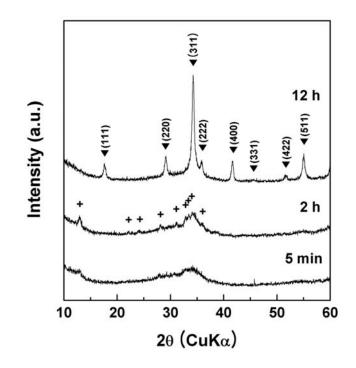


Fig. S4 XRD patterns of the powders prepared by reaction time-controlled experiments. All the diffraction peaks of powder obtained at a reaction time of 12 h are indexed to a cubic  $Zn_2SnO_4$  (JCPDS No. 24-1470).

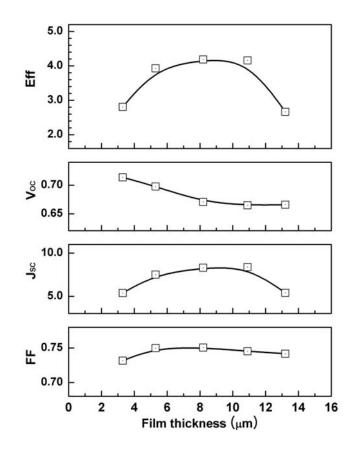
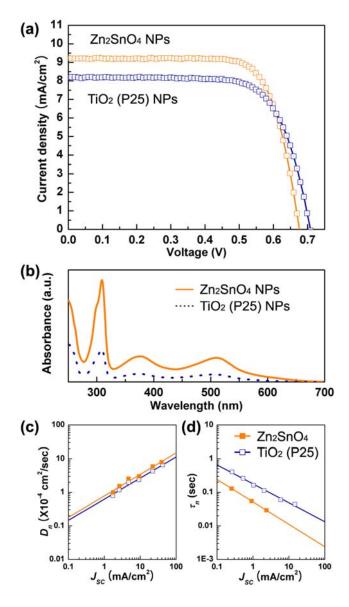


Fig. S5 J-V characteristics of the DSSCs employing  $Zn_2SnO_4$  NP films as a function of film

thickness.



**Fig. S6** Comparative studies of photovoltaic properties with DSSCs employing the ultra-fine  $Zn_2SnO_4$  NPs and the commercial TiO<sub>2</sub> NPs (P25). (a) Photocurrent density-voltage (*J-V*) characteristics of DSSCs, (b) optical absorption spectra of the desorbed dye molecules from the  $Zn_2SnO_4$  and TiO<sub>2</sub> photoelectrodes, and (c) Electron diffusion coefficients ( $D_n$ ) and (d) lifetimes ( $\tau_n$ ) as a function of short circuit current ( $J_{SC}$ ) that is obtained by the stepped light-induced transient measurements of photocurrent and photovoltage (SLIM-PCV)<sup>1</sup>.

1 S. Nakade, T. Kanzaki and Y. Wada, S. Yanagida, *Langmuir*, 2005, **21**, 10803.